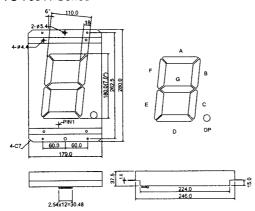
PartNO.: FYS-70011AX/BX-XX

DESCRIPTION

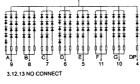
- 180.0mm (7.0")Single digit numeric display series.
- Standard brightness.
- Low current operation.
- Excellent character apperance.
- Easy mounting on P.C.boards or sockets

Package Dimensions &Internal Circuit Diagram

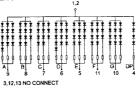












Notes:

- · All dimensions are in millimeters (inches)
- Tolerance is $\pm 0.25(0.01")$ unless otherwise noted.
- · Specificaions are subject to change whitout notice.

PartNO.: FYS-70011AX/BX-XX

: Absolute maximum ratings (Ta=25 $^{\circ}$ C)

Davarratas	Symbol	Test Condition	Val		
Parameter			Min	Max	Unit
Reverse Voltage	VR	IR=30μA	5		V
Forward Current	IF			30	mA
Power Dissipation	Pd			100	mW
Pulse Current	Ipeak	Duty=0.1mS, 1KHz		150	mA
Operating Temperature	Topr		-40	+85	° C
Storage Temperature	Tstr		-40	+85	° C

· -XX: Surface / Lens color:

Number	0	1	2	3	4	- 5
Ref Surface Color	White	Black	Gray	Red	Green	
Epoxy Color	Water clear	White diffused	Red Diffused	Green Diffused	Yellow Diffused	

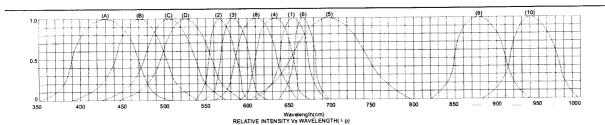
PartNO.: FYS-70011AX/BX-XX

■ Description:

· Color Code & Chip characteristics: (Test Condition: IF=20mA)

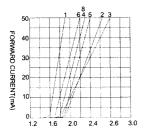
	Color Code & Chip characteristics: (lest Condition: IF=20mA)							
Emitting Color		Dice Material	Peak Wave Length(^λ _P)	Spectral Line halfwidth(Forward Voltage(VF) Unit:V		Luminous Intensity (Iv)	
į				∆λ1/2 ₎	Тур	Max	Unit:mcd	
Н	Red	GaP	700nm	90nm	2.20	2.50	5.0	
S, SR	Hi Red	AlGaAs,SH	660nm	20nm	1.80	2.20	15-20	
D	Super Red	AlGaAs,DH	660nm	20nm	1.80	2.20	20-30	
LR	Ultra Red	AlGaAs,DDH	660nm	20nm	1.90	2.40	26-38	
HR	HE Red	GaAsP	640nm	45nm	1.90	2.40	50-80	
Е	Orange	GaAsP	630nm	35nm	2.10	2.50	10-20	
Α	Amber	GaAsP	610nm	35nm	2.10	-2.50	15-20	
Υ	Yellow	GaAsP	590nm	35nm	2.10	2.50	15-20	
G	Green	GaP	570nm	30nm	2.20	2.50	14-18	
Ultra	brightness							
UH R	Ultra Hi Red	AlGaInP	645nm	20nm	2.10	2.50	80-150	
UE	Ultra Orange	AlGainP	630nm	20nm	2.10	2.50	180-210	
UA	Ultra Amber	AlGaInP	610nm	20nm	2.10	2.50	90-120	
UY	Ultra Yellow	AlGainP	590nm	20nm	2.10	2.50	150-200	
UG	Ultra Green	AlGainP	570nm	30nm	2.20	2.50	60-100	
PG	Ultra Pure Green	InGaN	520nm	36nm	2.80	3.80	260-310	
BG	Ultra Blue Green	InGaN	505nm	36nm	2.80	3.80	260-310	
В	Blue	InGaN	430nm	30nm	2.80	3.80	10-20	
LID	Litro Plus		470nm	30nm	2.80	3.80	80-90	
UB	Ultra Blue	InGaN	460nm	30nm	2.80	3.80	80-90	
V	UV	InGaN	405nm		2.80	3.80	5-8	
W	White	InGaN	X=0.29,y=0.30		- 2.80	3.80	180-200	
U W	Ultra White	InGaN	X=0.29,y=0.30		2.80	3.80	180-200	
Segment-to-Segment Luminous Intensity ratio(Iv-M) 1.5:1								

PartNO.: FYS-70011AX/BX-XX

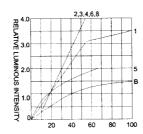


- (1) GaAsP/GaAs 655nm/Red
- (2) GaP 570nm/Yellow Green
- (3) GaAsP/GaP 585nm/Yellow
- (4) GaAsp/GaP 635nm/Orange & Hi-Eff Red
- (5) GaP 700nm/Bright Red
- (6) GaAlAs/GaAs 660nm/Super Red
- (8) GaAsP/GaP 610nm/Super Red

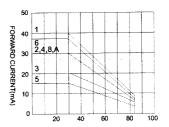
- (9) GaAlAs 880nm
- (10) GaAs/GaAs & GaAlAs/GaAs 940nm
- (A) GaN/SiC 430nm/Blue
- (B) InGaN/SiC 470nm/Blue
- (C) InGaN/SiC 505nm/Ultra Green
- (D) InGaAl/SiC 525nm/Ultra Green

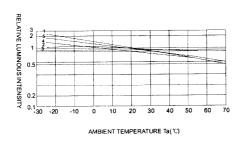


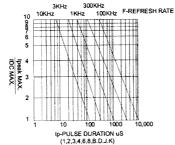
FORWARD VOLTAGE (Vf) FORWARD CURRENT VS. FORWARD VOLTAGE

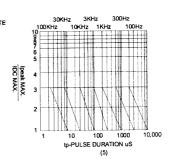


FORWARD CURRENT (mA) RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT









NOTE:25 °C free air temperature unless otherwise specified